L Number	Hits	Search Text	DB	Time stamp
22	4210514	@pd>20020514	USPAT;	2004/07/21 18:41
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
23	1	118/\$.ccls. and ((illuminat\$ near5 visual) same	USPAT;	2004/07/21 18:41
		(semiconductor))	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
24		(407/0 - 1 440/0 - 1) 1/4/1 1 1	IBM_TDB	
24	0	(427/\$.ccls. or 118/\$.ccls.) and (*diode*) and (thickness) and	USPAT;	2004/07/21 18:41
		(photoresist)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
25		(407/0 colo or 440/0 colo) and (*diad *)	IBM_TDB	
25	0	(427/\$.ccls. or 118/\$.ccls.) and (*diode*) and (thickness)	USPAT;	2004/07/21 18:41
			US-PGPUB;	
			EPO; JPO;	
Ī			DERWENT;	
26	397	(427/\$ cols or 118/\$ cols) and (nhatadiada) and (4hialmana)	IBM_TDB	0004/07/04 40 44
20	391	(427/\$.ccls. or 118/\$.ccls.) and (photodiode) and (thickness)	USPAT;	2004/07/21 18:41
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
27	5122	(118/320.ccls. or 118/326.ccls. or 118/712.ccls. or	IBM_TDB USPAT;	2004/07/24 40:44
	٠, ٠.٠	118/713.ccls. or 118/501.ccls. or 118/500.ccls.)	US-PGPUB;	2004/07/21 18:41
		1107000.0013.	EPO; JPO;	
			DERWENT;]
			IBM_TDB	
28	4083	(222/113.ccls. or 362/231.ccls. or 355/53.ccls. or	USPAT;	2004/07/21 18:41
		355/70.ccls. or 396/611.ccls.)	US-PGPUB;	2004/01/21 10.41
		,	EPO; JPO;	
			DERWENT:	
			IBM_TDB	
29	3708	156/379.ccls. or 427/8.ccls. or 427/9.ccls. or 427/10.ccls. or	USPAT;	2004/07/21 18:41
		427/240.ccls. or 427/425.ccls.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	45.5		IBM_TDB	
30	451303	process and chamber andnon-reflective and 118/\$.ccls.	USPAT;	2004/07/21 18:41
			US-PGPUB;	
	İ		EPO; JPO;	
			DERWENT;	
31	4557	(262)(445 and an 200)(447 and a constitution	IBM_TDB	
01	4557	(362/145.ccls. or 362/147.ccls. or 362/149.ccls. or	USPAT;	2004/07/21 18:41
İ		362/154.ccls. or 362/155.ccls. or 362/800.ccls. or	US-PGPUB;	
		362/803.ccls. or 362/458.ccls. or 362/253.ccls.)	EPO; JPO;	
ļ			DERWENT;	
32	174	118/677	IBM_TDB	0004/07/04 15
٥٢	174	110/077	USPAT;	2004/07/21 18:41
			US-PGPUB;	
ĺ	1		EPO; JPO;	
			DERWENT;	
33	1	(118/713.ccls.) and (illumination near3 intensity)	IBM_TDB	2004/07/04 40:44
	.	(, and (manimation nears intensity)	USPAT;	2004/07/21 18:41
			US-PGPUB; EPO; JPO;	
	1	I	DERWENT;	
			IBM TDB	
			IDINI I DR	

0.4	7 2422	Locale Linear Control of the Control	· · · · · · · · · · · · · · · · · · ·	
34	2168	356/\$.ccls. and (illuminat\$4 near3 intens\$4)	USPAT;	2004/07/21 18:41
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
72	9851	"advanced micro devices"	USPAT;	2004/07/21 18:42
ľ			US-PGPUB	
81	2594	250/205	USPAT;	2004/07/21 18:42
			US-PGPUB:	
			EPO; JPO;	
			DERWENT;	
	i		IBM_TDB	
83	112	((250/205).CCLS.) and (coating or dispensing or coat or	USPAT;	2004/07/21 18:43
		dispense)	US-PGPUB;	
			EPO; JPO;	
	İ		DERWENT;	
İ			IBM_TDB	
21	965	subramanian.in.	USPAT;	2004/07/21 18:43
			US-PGPUB	2004/01/21 10.43
35	339	@pd>20020514 and (118/50.ccls. or 118/52.ccls. or	USPAT;	2004/07/21 18:43
		118/50.1.ccls. or 118/56.ccls.)	US-PGPUB;	2007/01/21 10:43
		,	EPO; JPO;	
			DERWENT;	
			IBM TDB	
36	626	@pd>20020514 and (118/320.ccls. or 118/326.ccls. or	USPAT;	2004/07/04 40:44
	020	118/712.ccls. or 118/713.ccls. or 118/501.ccls. or	1	2004/07/21 18:44
]	118/500.ccls.)	US-PGPUB;	· · · · · · · · · · · · · · · · · · ·
	1	110,000.0013.)	EPO; JPO;	
			DERWENT;	
37	1351	@pd>20020514 and (222/113.ccls. or 362/231.ccls. or	IBM_TDB	0004/07/04 40 44
1 07	1331	355/53.ccls. or 355/70.ccls. or 396/611.ccls.)	USPAT;	2004/07/21 18:44
		333/33.ccis. 01 333/70.ccis. 01 390/01 1.ccis.)	US-PGPUB;	1
			EPO; JPO;	
	i		DERWENT;	
38	588	@md>000000514 amd (450/070 and a 407/0 a	IBM_TDB	
36	500	@pd>20020514 and (156/379.ccls. or 427/8.ccls. or	USPAT;	2004/07/21 18:45
]	427/9.ccls. or 427/10.ccls. or 427/240.ccls. or 427/425.ccls.)	US-PGPUB;	
	1		EPO; JPO;	
			DERWENT;	
20	4004	@- 45 00000544	IBM_TDB	
39	1001	@pd>20020514 and (362/145.ccls. or 362/147.ccls. or	USPAT;	2004/07/21 18:45
		362/149.ccls. or 362/154.ccls. or 362/155.ccls. or	US-PGPUB;	
		362/800.ccls. or 362/803.ccls. or 362/458.ccls. or	EPO; JPO;	
]	j l	362/253.ccls.)	DERWENT;	
40		440/6	IBM_TDB	
40	17	118/\$.ccls. and ((visual near3 inspection) same (chuck or	USPAT;	2004/07/21 18:45
		holder or table))	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		440/0	IBM_TDB	,
41	11	118/\$.ccls. and ((visual near3 inspection) same	USPAT;	2004/07/21 18:45
		(semiconductor))	US-PGPUB;	
	}		EPO; JPO;	
			DERWENT,	
			IBM_TDB	
42	97	118/\$.ccls. and ((illuminat\$) same (semiconductor))	USPAT;	2004/07/21 18:45
		··	US-PGPUB;	_ [
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
43	191	118/\$.ccls. and ((illuminat\$) same (chamber))	USPAT;	2004/07/21 18:45
			US-PGPUB;	
,			EPO; JPO;	
	İ		DERWENT;	
			IBM_TDB	

44	717	(== : +: : : : : : : : : : : : : : : : :	USPAT;	2004/07/21 18:45
	1	or "light emitting diodes") and controller	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
45	1	"5843527".PN.	USPAT	2004/07/21 18:45
46	222	(427/\$.ccls. or 118/\$.ccls.) and (LED or "light emitting diode"	USPAT;	2004/07/21 18:45
		or "light emitting diodes") and (controller same (input or	US-PGPUB;	
		output))	EPO; JPO;	
			DERWENT;	
1			IBM TDB	
47	1	6122042.pn.	USPAT	2004/07/21 18:45
48	1	6122042.pn. and (coat or coating)	USPAT	2004/07/21 18:45
49	61	(427/\$.ccls. or 118/\$.ccls.) and (photodiode) and (thickness)	USPAT;	
70		and photoresist		2004/07/21 18:45
	•	and photoresist	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
50		(440/0 1) 1/ 1/ 1/ 1/ 1/ 1/ 1/ 1/ 1/ 1/ 1/ 1/ 1/	IBM_TDB	
50	50	(118/\$.ccls.) and (photodiode) and (thickness) and controller	USPAT;	2004/07/21 18:46
	1		US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	1		IBM_TDB	
51	11	"5985357"	USPAT	2004/07/21 18:46
52	97	process and chamber and anti-reflective and 118/\$.ccls.	USPAT;	2004/07/21 18:46
			US-PGPUB;	200 1101721 10.40
			EPO; JPO;	
			DERWENT;	
	1		IBM_TDB	
53	1	4713140.pn.	USPAT	2004/07/24 40:46
54	1	4696209.pn.	1	2004/07/21 18:46
55	1	4227347.pn.	USPAT	2004/07/21 18:46
56	1		USPAT	2004/07/21 18:46
50	13	process and chamber and non-reflective and 118/\$.ccls.	USPAT;	2004/07/21 18:46
			US-PGPUB;	
			EPO; JPO;	
1			DERWENT;	
			IBM_TDB	
57	4	process and chamber and nonreflective and 118/\$.ccls.	USPAT;	2004/07/21 18:46
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
58	1569	438/16	USPAT;	2004/07/21 18:46
			US-PGPUB:	
-			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
59	162	438/16 and reflectivity	USPAT;	2004/07/24 40:46
		1957 19 und Tonoccivity		2004/07/21 18:46
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
60		400/40 J (Illumination of the Inc.)	IBM_TDB	
60	23	438/16 and (illumination near3 intensity)	USPAT;	2004/07/21 18:46
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
61	28	438/16 and (illuminat\$4 near3 intens\$4)	USPAT;	2004/07/21 18:46
1		·	US-PGPUB;	
]		EPO; JPO;	
			DERWENT;	
1		, in	IBM TDB	

r**				
62	5	(118/712.ccls.) and (illumination near3 intensity)	USPAT; US-PGPUB;	2004/07/21 18:46
			EPO; JPO;	
1			DERWENT;	
			IBM_TDB	
63	679	356/\$.ccls. and (illuminat\$4 near3 intens\$4) and	USPAT;	2004/07/21 18:47
		semiconductor	US-PGPUB;	2004/01/21 10.4/
			EPO; JPO;	
			DERWENT;	
1			IBM_TDB	
64	347	356/\$.ccls. and (illuminat\$4 near3 intens\$4) and	USPAT;	2004/07/21 18:47
		semiconductor and thickness	US-PGPUB;	200 (101/21 10.17
1			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
65	18	"6016562"	USPAT	2004/07/21 18:47
66	1398	((118/712) or (118/713)).CCLS.	USPAT;	2004/07/21 18:47
ŀ			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
107		//ogo4007//\	IBM_TDB]
67	1	("6031607").PN.	USPAT	2004/07/21 18:47
68	8	356/\$.ccls. and (adjustable near3 intens\$4) and	USPAT;	2004/07/21 18:48
1		semiconductor and thickness	US-PGPUB;]
ľ			EPO; JPO;	
			DERWENT;	
69	26	356/\$ cols and /adjustable near 2 illuminate (1) and	IBM_TDB	0004/07/74
03	20	356/\$.ccls. and (adjustable near3 illuminat\$4) and semiconductor and thickness	USPAT;	2004/07/21 18:48
		semiconductor and thickness	US-PGPUB;	
			EPO; JPO;	
	1		DERWENT;	
70	88	356/\$.ccls. and (variable near3 intens\$4) and	IBM_TDB USPAT;	2004/07/21 18:48
'		semiconductor and thickness	US-PGPUB;	2004/07/21 10:46
	1	Torridord and thompson	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
71	1	("6376013").PN.	USPAT	2004/07/21 18:48
73	165	subramanian.in. and (advanced near2 micro)	USPAT;	2004/07/21 18:48
		,	US-PGPUB	
74	7444	advanced.asn. and micro.asn. and devices.asn.	USPAT;	2004/07/21 18:51
			US-PGPUB	
75	154	advanced.asn. and micro.asn. and devices.asn. and	USPAT;	2004/07/21 18:51
70	_ [(396/\$.ccls. or 118/\$.ccls. or 427/\$.ccls. or 131/\$.ccls.)	US-PGPUB	
76	8	(("5968268") or ("5845170") or ("5720814") or ("5718992") or	USPAT	2004/07/21 18:51
		("5393624") or ("5366757") or ("5127362") or	,	
77	44	("5089305")).PN.		
77	14	(("5962070") or ("5942037") or ("5885755") or ("5885661") or	USPAT	2004/07/21 18:51
		("5826130") or ("5820677") or ("5678116") or ("5625433") or		
		("5555234") or ("5474877") or ("5275658") or ("5089305") or ("4997552") or ("4564280")).PN.		
78	1	"20020029744"	He bonin	2004/07/04 40 54
79	10	356/\$.ccls. and (compensation near3 illuminat\$4) and	US-PGPUB	2004/07/21 18:51
1	'0	semiconductor and thickness	USPAT; US-PGPUB:	2004/07/21 18:51
			EPO; JPO;	
!			DERWENT;	
			IBM_TDB	
80	97	356/455	USPAT;	2004/07/21 18:51
] [US-PGPUB;	2007/01/21 10:01
			EPO; JPO;	
	[DERWENT;	
			IBM TDB	
			··	

82	69	(356/455).CCLS.	USPAT;	2004/07/21 18:51
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
84	127	((250/205).CCLS.) and (coating or dispensing or coat or	USPAT;	2004/07/21 18:51
]		dispense)	US-PGPUB;	
İ	ļ		EPO; JPO;	
			DERWENT;	
			IBM_TDB	
85	1214	(250/205).CCLS.	USPAT;	2004/07/21 18:52
			US-PGPUB;	
İ			EPO; JPO;	
			DERWENT;	
L			IBM_TDB	